

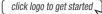
Vishay General Semiconductor

Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low $V_F = 0.41 \text{ V}$ at $I_F = 5 \text{ A}$



DESIGN SUPPORT TOOLS





PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 7.5 A				
V_{RRM}	45 V				
I _{FSM}	100 A				
V_F at $I_F = 7.5$ A	0.49 V				
T _{OP} max. (AC mode)	150 °C				
T _J max. (DC forward current)	200 °C				
Package	D ² PAK (TO-263AB)				
Circuit configurations	Common cathode				

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C



- T_J 200 °C max. in solar bypass mode application
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER		SYMBOL	VBT1545CBP	UNIT			
Maximum repetitive peak reverse voltage		V_{RRM}	45	V			
Maximum average forward rectified current (fig. 1)	per device	I (1)	15	Α			
	per diode	- I _{F(AV)} ⁽¹⁾	7.5				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode			100	Α			
Operating junction and storage temperature range (AC mode)			-40 to +150	°C			
Junction temperature in DC forward current without reverse bias, t ≤ 1 h		T _J ⁽²⁾	≤ 200	°C			

Notes

- (1) With heatsink
- (2) Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CC	TEST CONDITIONS		TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C T _A = 125 °C	V _F ⁽¹⁾	0.49	-	V	
	I _F = 7.5 A			0.55	0.63		
	I _F = 5 A			0.41	-		
	I _F = 7.5 A			0.49	0.57		
Reverse current per diode	\/ 4E\/	T _A = 25 °C	I _R ⁽²⁾	-	500	μΑ	
	V _R = 45 V	T _A = 125 °C		5	15	mA	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms



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THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VBT1545CBP	UNIT	
Typical thermal resistance	per diode	$R_{ heta JC}$	3.5	°C/W	
	per device		2.5	C/VV	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VBT1545CBP-E3/4W	1.38	4W	50/tube	Tube	
TO-263AB	VBT1545CBP-E3/8W	1.38	8W	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

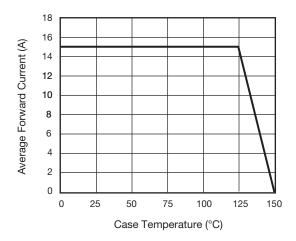


Fig. 1 - Maximum Forward Current Derating Curve

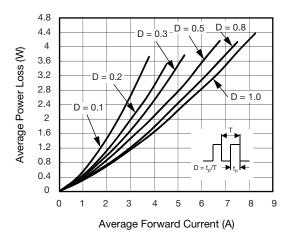


Fig. 2 - Forward Power Loss Characteristics Per Diode

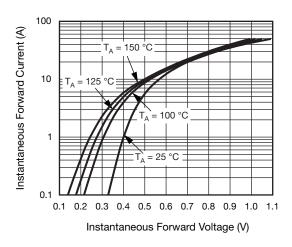


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

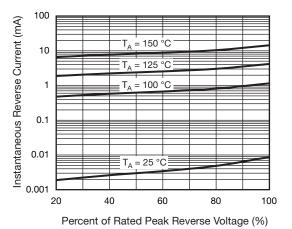


Fig. 4 - Typical Reverse Characteristics Per Diode



0.095 (2.41)

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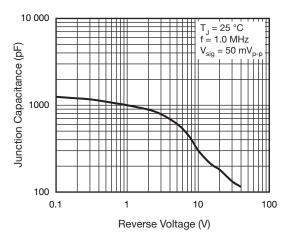


Fig. 5 - Typical Junction Capacitance Per Diode

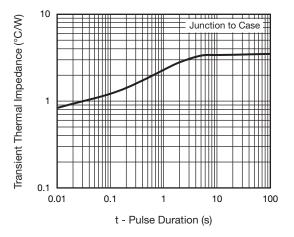


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

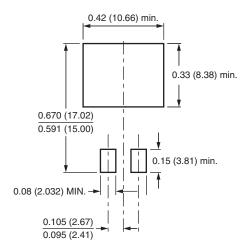
D²PAK (TO-263AB)

0.411 (10.45) 0.190 (4.83) 0.380 (9.65) 0.055 (1.40) 0.160 (4.06) 0.045 (1.14) 0.245 (6.22) MIN. 0.055 (1.40) 0.360 (9.14) 0.047 (1.19) 0.320 (8.13) 0.624 (15.85) 0.591 (15.00) 0 to 0.01 (0 to 0.254) 0.110 (2.79) 0.090 (2.29) 0.037 (0.940) 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56)

0.205 (5.20)

0.195 (4.95)

Mounting Pad Layout



0.110 (2.79)



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